

US006791119B2

(12) United States Patent

Slater, Jr. et al.

(10) Patent No.: US 6,791,119 B2

(45) **Date of Patent:** Sep. 14, 2004

(54) LIGHT EMITTING DIODES INCLUDING MODIFICATIONS FOR LIGHT EXTRACTION

(75) Inventors: David B. Slater, Jr., Raleigh, NC (US);

Robert C. Glass, Chapel Hill, NC (US); Charles M. Swoboda, Morrisville, NC (US); Bernd Keller, Goleta, CA (US); James Ibbetson, Goleta, CA (US); Brian Thibeault, Santa Barbara, CA (US); Eric J. Tarsa, Goleta, CA (US)

(73) Assignee: Cree, Inc., Durham, NC (US)

(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35

U.S.C. 154(b) by 0 days.

(21) Appl. No.: 10/057,821

(22) Filed: Jan. 25, 2002

(65) Prior Publication Data

US 2002/0123164 A1 Sep. 5, 2002

Related U.S. Application Data

(60) Provisional application No. 60/307,235, filed on Jul. 23, 2001, and provisional application No. 60/265,707, filed on Feb. 1, 2001.

| (51) | Int. Cl | H01L 33/00 |
|------|-----------------|--------------------------------|
| (52) | U.S. Cl | 257/99 ; 257/95; 257/98 |
| (58) | Field of Search | |

(56) References Cited

U.S. PATENT DOCUMENTS

| 4,918,497 | 4/1990 | Edmond 357/17 |
|-------------|---------|-----------------------|
| 4,966,862 A | 10/1990 | Edmond 437/100 |
| 5,006,908 A | 4/1991 | Matsuoka et al 357/17 |
| 5,027,168 A | 6/1991 | Edmond 357/17 |
| 5,087,949 A | 2/1992 | Haitz 357/17 |
| 5,187,547 A | 2/1993 | Niina et al 257/77 |
| 5,210,051 A | 5/1993 | Carter, Jr 437/107 |
| 5,237,182 A | 8/1993 | Kitagawa et al 257/15 |

(List continued on next page.)

FOREIGN PATENT DOCUMENTS

| EP | 0 051 172 | 5/1982 |
|----|--------------|---------|
| EP | 0 961 328 A2 | 12/1999 |
| EP | 1 168 460 A2 | 1/2002 |
| GB | 2 346 480 A | 8/2000 |
| JP | 56-131977 | 10/1981 |

(List continued on next page.)

OTHER PUBLICATIONS

OSRAM Enhances Brightness of Blue InGaN LEDs, Compound Semiconductor, vol. 7, No. 1, Feb. 2001, p. 7. Craford, Outlook for AllnGaP Technology, Presentation, Strategies in Light 2000.

Krames et al., High–Power Truncated–Inverted–Pyramid $(Al_xGa_{1-x})_{0.5}In_{0.5}P/GaP$ Light–Emitting Diodes Exhibiting > 55External Quantum Efficiency, Applied Physics Letters, vol. 75, No. 16, Oct. 18, 1999, pp. 2365–2367.

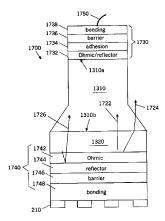
(List continued on next page.)

Primary Examiner—Jerome Jackson (74) Attorney, Agent, or Firm—Myers Bigel Sibley & Sajovec

(57) ABSTRACT

Light emitting diodes include a substrate having first and second opposing faces and that is transparent to optical radiation in a predetermined wavelength range and that is patterned to define, in cross-section, a plurality of pedestals that extend into the substrate from the first face towards the second face. A diode region on the second face is configured to emit light in the predetermined wavelength range, into the substrate upon application of voltage across the diode region. A mounting support on the diode region, opposite the substrate is configured to support the diode region, such that the light that is emitted from the diode region into the substrate, is emitted from the first face upon application of voltage across the diode region. The first face of the substrate may include therein a plurality of grooves that define the plurality of triangular pedestals in the substrate. The grooves may include tapered sidewalls and/or a beveled floor. The first face of the substrate also may include therein an array of via holes. The via holes may include tapered sidewalls and/or a floor.

104 Claims, 15 Drawing Sheets





U.S. PATENT DOCUMENTS

| 5,247,533 | A | | 9/1993 | Okazaki et al 372/45 |
|--------------|------------|---|---------|---------------------------|
| 5,338,994 | Α | | 8/1994 | Lezan et al 307/86 |
| 5,369,289 | Α | | 11/1994 | Tamaki et al 257/99 |
| 5,393,993 | Α | | 2/1995 | Edmond et al 257/77 |
| 5,416,342 | Α | | 5/1995 | Edmond et al 257/76 |
| 5,523,589 | Α | | 6/1996 | Edmond et al 257/77 |
| 5,585,648 | Α | | 12/1996 | Tischler 257/77 |
| 5,604,135 | Α | | 2/1997 | Edmond et al 437/22 |
| 5,631,190 | Α | | 5/1997 | Negley 438/33 |
| 5,718,760 | Α | | 2/1998 | Carter et al 117/84 |
| 5,739,554 | Α | | 4/1998 | Edmond et al 257/103 |
| 5,760,479 | Α | | 6/1998 | Yang et al. |
| 5,767,581 | A | | 6/1998 | Nakamura et al 257/749 |
| 5,777,350 | Α | | 7/1998 | Nakamura et al 257/96 |
| 5,779,924 | Α | | 7/1998 | Krames et al 216/24 |
| 5,846,694 | Α | * | 12/1998 | Strand et al 430/321 |
| 5,912,477 | A | | 6/1999 | Negley 257/95 |
| 5,917,202 | Α | | 6/1999 | Haitz et al 257/98 |
| 5,952,681 | A | | 9/1999 | Chen 257/89 |
| 6,015,719 | Α | | 1/2000 | Kish, Jr. et al 438/29 |
| 6,031,243 | Α | * | 2/2000 | Taylor 257/98 |
| 6,046,465 | Α | | 4/2000 | Wang et al 257/98 |
| 6,091,085 | Α | | 7/2000 | Lester 257/98 |
| 6,097,041 | Α | | 8/2000 | Lin et al 257/98 |
| 6,118,259 | Α | | 9/2000 | Bucks et al 323/312 |
| 6,120,600 | Α | | 9/2000 | Edmond et al 117/89 |
| 6,121,636 | Α | | 9/2000 | Morita et al 257/99 |
| 6,121,637 | Α | | 9/2000 | Isokawa et al 257/99 |
| 6,133,589 | A | | 10/2000 | Krames et al 257/103 |
| 6,139,166 | Α | | 10/2000 | Marshall et al 362/231 |
| 6,147,458 | Α | | 11/2000 | Bucks et al 325/225 |
| 6,169,294 | B1 | | 1/2001 | Biing-Jye et al 257/79 |
| 6,177,688 | B 1 | | 1/2001 | Linthicum et al 257/77 |
| 6,187,606 | B1 | | 2/2001 | Edmond et al 438/46 |
| 6,194,742 | B1 | | 2/2001 | Kern et al 257/94 |
| 6,201,264 | B1 | | 3/2001 | Khare et al 257/97 |
| 6,204,523 | B1 | | 3/2001 | Carey et al 257/98 |
| 6,222,207 | B1 | | 4/2001 | Carter-Coman et al 257/98 |
| 6,229,160 | B 1 | | 5/2001 | Krames et al 257/94 |
| 6,455,878 | B 1 | | 9/2002 | Bhat et al 257/99 |
| 2003/0006418 | A 1 | | 1/2003 | Emerson et al 257/79 |
| 2003/0025212 | A 1 | | 2/2003 | Bhat et al. |
| | | | | |

FOREIGN PATENT DOCUMENTS

| JP | 61110476 | 5/1986 |
|----|--------------|---------|
| JP | 1-225377 | 9/1989 |
| JP | 06-232510 | 8/1994 |
| JP | 07-235729 | 9/1995 |
| JP | 08-321660 | 12/1996 |
| JP | 9-82587 | 3/1997 |
| JP | 09-223846 | 8/1997 |
| JP | 10-163530 | 6/1998 |
| JP | 10-233549 | 9/1998 |
| JP | 10-256604 | 9/1998 |
| JP | 11-150302 A | 6/1999 |
| JP | 11-191641 | 7/1999 |
| JP | 11-220168 A | 8/1999 |
| JP | 2000-77713 A | 3/2000 |
| JP | 2000-195827 | 7/2000 |
| | | |

| WO | WO 00/33365 | 6/2000 |
|----|----------------|--------|
| WO | WO 01/47039 A1 | 6/2001 |

OTHER PUBLICATIONS

Lambrecht et al., Band Structure Interpretation of the Optical Transitions Between Low-Lying Conduction Bands in n-Type Doped SiC Polytypes, Materials Science Forum, vols. 264–268, 1998, pp. 271–274.

Craford, Overview of Device Issues in High–Brightness Light–Emitting Diodes, Chapter 2, High Brightness Light Emitting Diodes: Semiconductors and Semimetals, vol. 48, Stringfellow et al. ed., Academic Press, 1997, pp. 47–63. Yoo et al., Bulk Crystal Growth of 6H–SiC on Polytype–Controlled Substrates Through Vapor Phase and Characterization, Journal of Crystal Growth, vol. 115, vol. 1991, pp. 733–739.

Biederman, *The Optical Absorption Bands and Their Anisotropy in the Various Modifications of SiC*, Solid State Communications, vol. 3, 1965, pp. 343–346.

U.S. application Ser. No. 09/154,363, entitled *Vertical Geometry InGaN LED*.

U.S. application Ser. No. 60,411,980, filed Sep. 19, 2002, *Phosphor–Coated Light Emitting Diodes Including Tapered Sidewalls, and Fabrication Methods.*

U.S. application Ser. No. 10/003,331, filed Oct. 31, 2001, Low Temperature Formation of Backside Ohmic Contacts for Vertical Devices.

U.S. application Ser. No. 60/294,445, filed May 30, 2001, *Multi-Quantum Well Light Emitting Diode Structure*.

U.S. application Ser. No. 60/294,378, filed May 30, 2001, Light Emitting Diode Structure With Multi–Quantum Well and Superlattice Structure.

U.S. application Ser. No. 60/294,308, filed May 30, 2001, Light Emitting Diode Structure With Superlattice Structure. U.S. application Ser. No. 09/787,189, filed Mar. 15, 2001, Low Temperature Formation of Backside Ohmic Contacts for Vertical Devices.

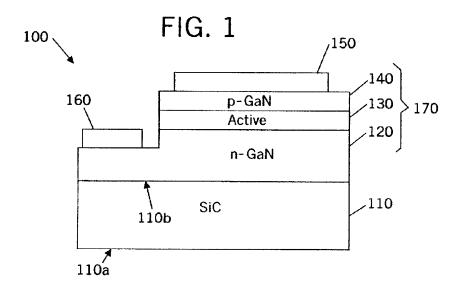
Invitation to Pay Additional Fees, Annex to Form PCT/ISA/206, Communication Relating to the Results of the Partial International Search, PCT/US02/02849, Aug. 26, 2002. International Search Report, PCT/US02/02849, Dec. 2, 2002.

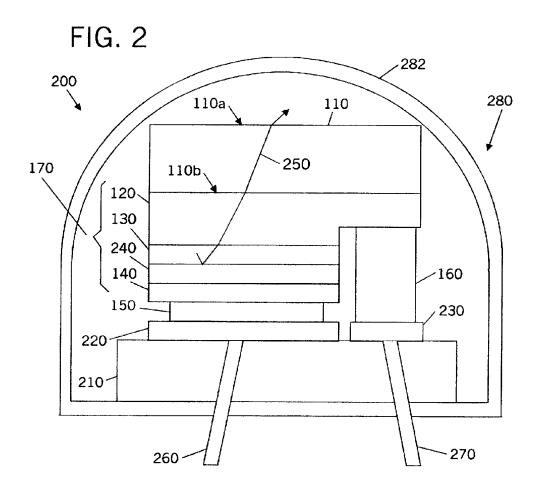
Mensz et al., $\ln_x GA_{1-x}N/Al_y GA_{1-y}N$ Violet Light Emitting Diodes with Reflective p–Contacts for High Single Sided Light Extraction, Electronics Letters, vol. 33, No. 24, Nov. 20, 1997, pp. 2066–2068.

Honma et al., Evaluation of Barrier Metals of Solder Bumps for Flip-Chip Interconnection, Electronic Manufacturing Technology Symposium, 1995, Proceedings of 1995 Japan International, 18th IEEE/CPMT, Dec. 4, 1995, pp. 113–116. Lee et al., Bonding of InP Laser Diodes by Au–Sn Solder and Tungsten–Based Barrier Metallization Schemes, Semiconductor Science and Technology, vol. 9, No. 4, Apr. 1994, pp. 379–386.

* cited by examiner

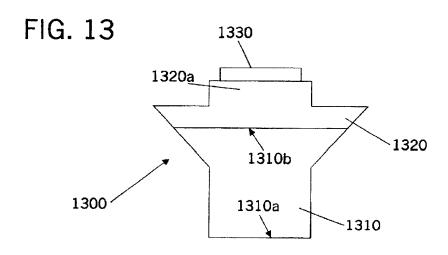






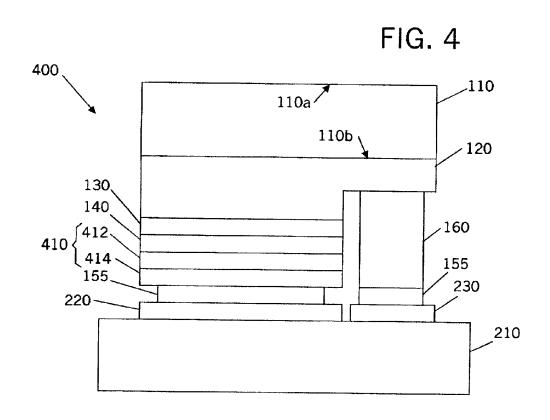
Sep. 14, 2004

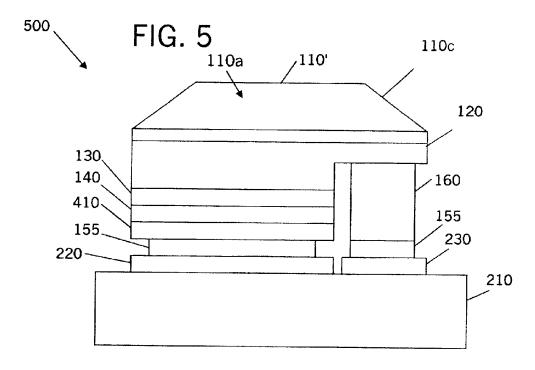
FIG. 3 160' 110a /110b 150 -





Sep. 14, 2004







DOCKET

Explore Litigation Insights



Docket Alarm provides insights to develop a more informed litigation strategy and the peace of mind of knowing you're on top of things.

Real-Time Litigation Alerts



Keep your litigation team up-to-date with **real-time** alerts and advanced team management tools built for the enterprise, all while greatly reducing PACER spend.

Our comprehensive service means we can handle Federal, State, and Administrative courts across the country.

Advanced Docket Research



With over 230 million records, Docket Alarm's cloud-native docket research platform finds what other services can't. Coverage includes Federal, State, plus PTAB, TTAB, ITC and NLRB decisions, all in one place.

Identify arguments that have been successful in the past with full text, pinpoint searching. Link to case law cited within any court document via Fastcase.

Analytics At Your Fingertips



Learn what happened the last time a particular judge, opposing counsel or company faced cases similar to yours.

Advanced out-of-the-box PTAB and TTAB analytics are always at your fingertips.

API

Docket Alarm offers a powerful API (application programming interface) to developers that want to integrate case filings into their apps.

LAW FIRMS

Build custom dashboards for your attorneys and clients with live data direct from the court.

Automate many repetitive legal tasks like conflict checks, document management, and marketing.

FINANCIAL INSTITUTIONS

Litigation and bankruptcy checks for companies and debtors.

E-DISCOVERY AND LEGAL VENDORS

Sync your system to PACER to automate legal marketing.

